

Niko Semiconductor Co., LTD.

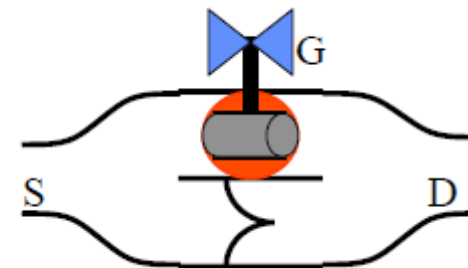
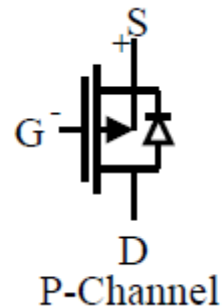
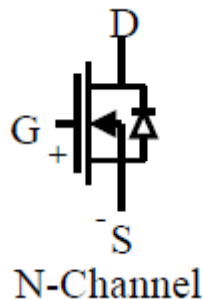
**Niko-sem  
MOSFET  
Introduce**

*We Power Hi-Tech.*

*Niko-Sem*

# What is a MOSFET ?

- A MOSFET is an electrical switch
- It has three terminals - Drain (D), Source (S), and Gate(G)
- The switch is closed (turned on) by applying Voltage on the Gate relative to the Source
  - N-Channel - Gate positive with respect to the source
  - P-Channel - Gate negative with respect to Source
- It can be turned slightly on by applying a small Voltage from Gate to Source
- The Channel (connection between the Drain and Source when the switch is turned on) can conduct Current in either direction
- A Diode bypasses the switch in one direction

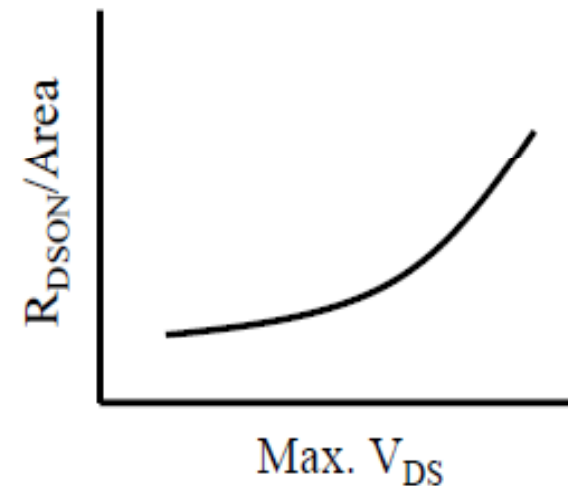
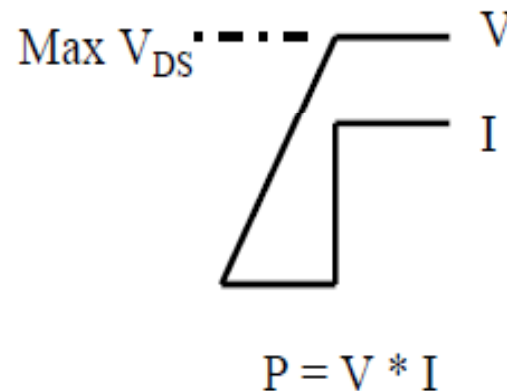
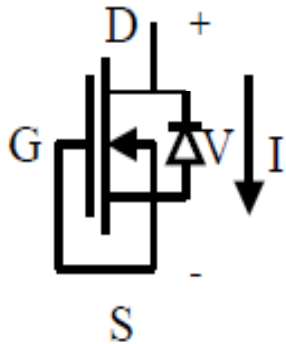


# Major MOSFET Parameter

1. Package
2. Channel Type
3.  $V_{ds}$
4.  $V_{gs}$
5.  $I_d$
6.  $R_{ds(on)}$

# Maximum Drain-Source Voltage - $V_{DS}$

- Maximum  $V_{DS}$  is the highest drain to source voltage a MOSFET can block
- As the voltage on the drain (relative to the source) rises, it is blocked until the Maximum  $V_{DS}$  rating is exceeded, then Avalanche occurs
- Maximum  $V_{DS}$  is the first consideration in designing in a MOSFET
- The lower the breakdown voltage, the more cost efficient the MOSFET is.



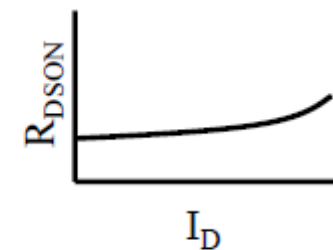
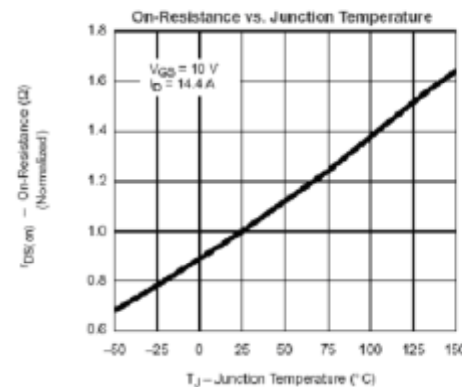
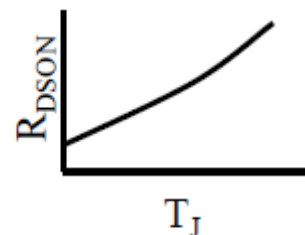
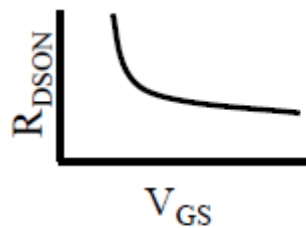
# Maximum Drain Current - $I_D$

- Maximum Drain Current ( $I_D$ ) is the most current a MOSFET can handle through it between Drain and Source when it is turned on without risking failure
  - It is based on the current which will drive the junction temperature ( $T_J$ ) to its maximum, 150 °C usually
- It is specified at:
  - Ambient Temperature ( $T_A$ ) = 25°C, the  $I_D$  spec will be lower
  - Case Temperature ( $T_C$ ) = 25°C, the  $I_D$  spec will be higher

*More argument on this spec due to specified at different condition!*

# MOSFET turn on Resistance

- $R_{\text{DSON}}$  is the Resistance through a MOSFET when it is on
- $R_{\text{DSON}}$  is important because it determines the:
  - Voltage drop across the MOSFET at a particular Current:  $V = I * R$
  - Power dissipated (heat generated) by the MOSFET in the on state:  $P = I^2 * R$
- The  $R_{\text{DSON}}$  is dependent on Gate to Source Voltage ( $V_{\text{GS}}$ ), Junction Temperature ( $T_{\text{J}}$ ), and Drain Current ( $I_{\text{D}}$ )
  - $R_{\text{DSON}}$  is specified as typical and maximum at several Gate to source voltages
  - $R_{\text{DSON}}$  is specified at  $T_{\text{J}} = 25^{\circ}\text{C}$ . It increases roughly 1.6 times from 25 to  $150^{\circ}\text{C}$
  - $R_{\text{DSON}}$  is specified at maximum  $I_{\text{D}}$



# Where to look for MOSFET business

Whether the system is Computer, Telecom, Portables..., there are only 3 basic applications

- **Switching Application** (like Buck, boost... converter)

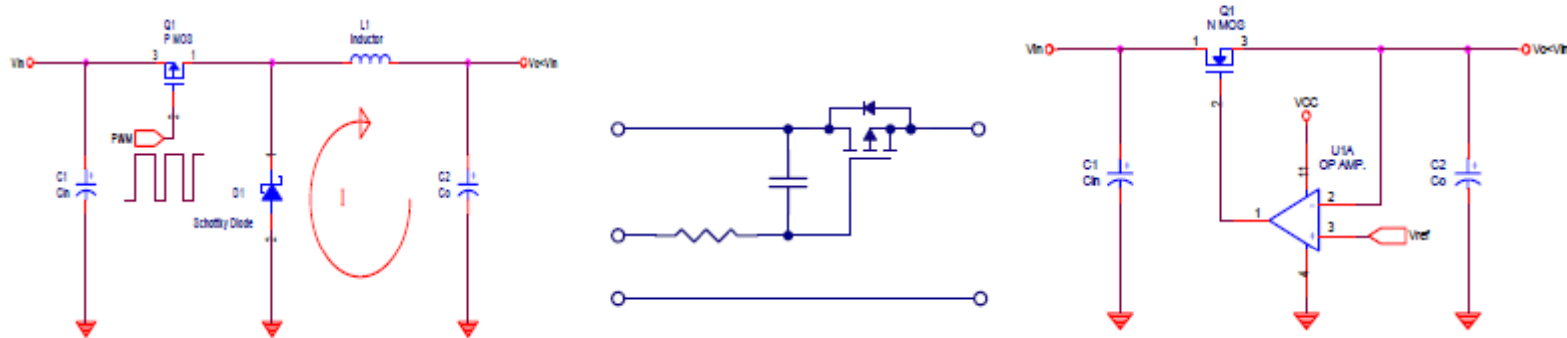
- Key Parameters -  $V_{DS}$ ,  $V_{GS}$ ,  $R_{DSon}$ ,  $Q_g$ ,  $Q_{gd}$ ,  $R_G$

- **Load Switch Application**

- Key Parameters -  $V_{DS}$ ,  $V_{GS}$ ,  $R_{DSon}$ ,  $I_{DMax}$ ,  $V_{GSth}$

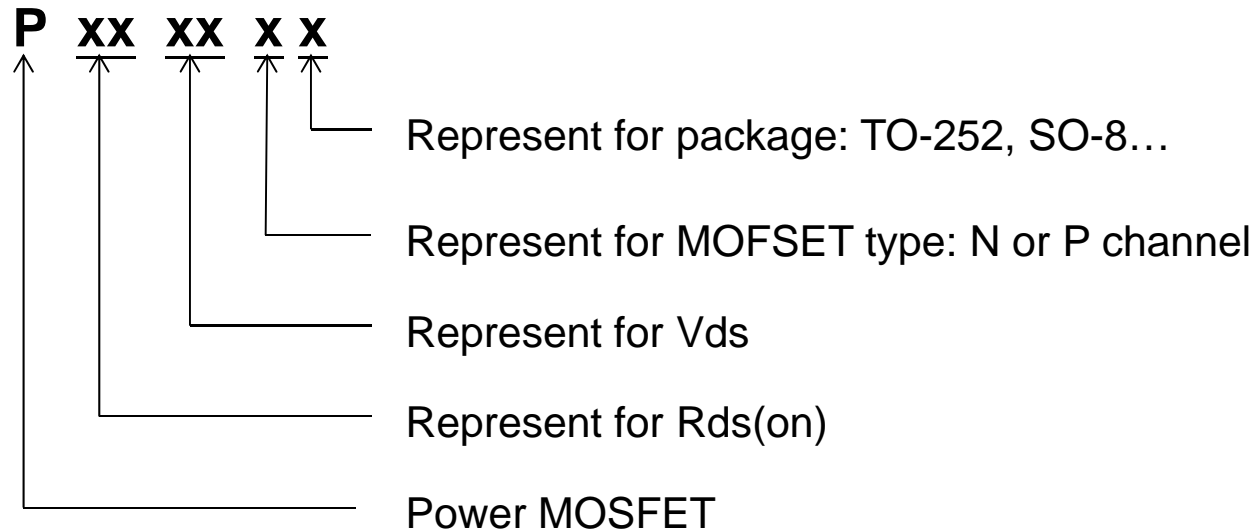
- **Linear Mode Application** (linear regulator, linear amplifier...)

- Key Parameters -  $R_{\theta JC}$



# LV/MV MOSFET P/N Definition

**P2003BDG: MOSFET 20m ohm, 30V, TO-252**

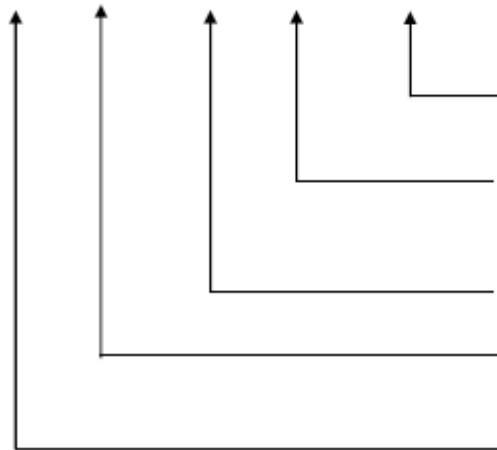




# HV MOSFET P/N Definition

**P0460ATF : MOSFET 600V 4A TO-220F**

P XX XX X XX



Represent for Package Code : TF( TO-220F),  
D ( TO-252), I (TO-251)

Represent for Version: A~Z

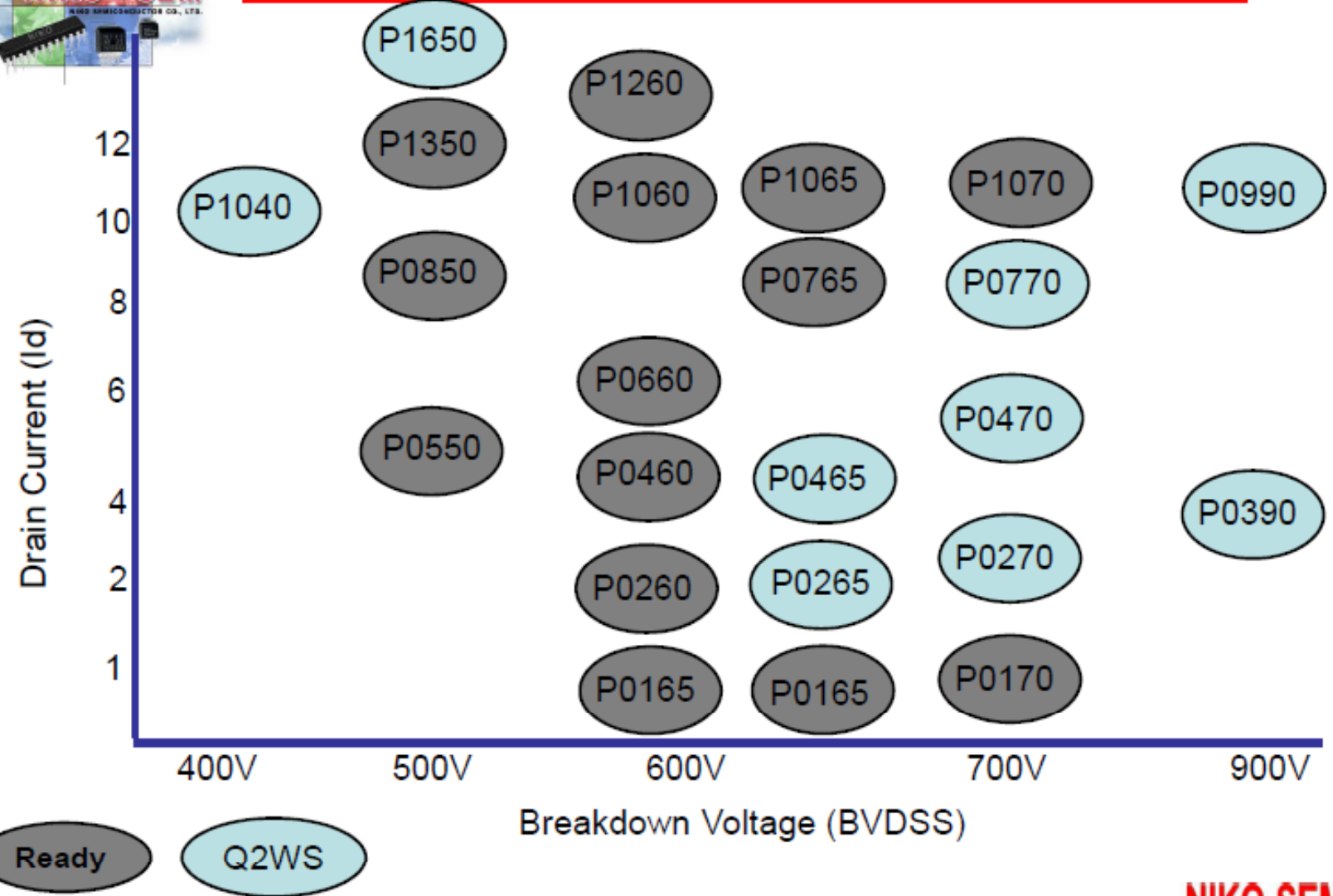
Represent for Voltage/ Ex: 60 → 600V ; 65→650V

Represent for Current/ Ex: 04 → 4A

Power MOSFET



# NIKO SEMICONDUCTOR CO.,LTD.



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# 400V~700V part list

Part NO.	VDS (V)	ID (A)	RDS(on) $\Omega$ max 10V (Id=50%)	MP Schedule	Package							Remark	
					TO-92	TO-252	TO-251	TO-262	TO-263	TO-220	TO-220F		TO-3P/247
P0640	400	6	1	Q2		V▲					V▲		
P1040	400	10	0.55	Q2							V▲		
P0550	500	5	1.5	Now		V▲	V▲			V▲	V▲		
P0550B	500	5	1.75	Q1		V▲	V▲			V▲	V▲		
P0850	500	8	0.85	Now						V▲	V▲		
P1350	500	13	0.52	Now							V▲		
P1650	500	16	0.38	Q2						V▲	V▲	V▲	PFC Switch
P0160	600	1	12	Now	V▲	V▲	V▲						
P0260	600	2	4.4	Now		V▲	V▲				V▲		
P0460	600	4	2	Now		V▲	V▲			V▲	V▲		
P0460B	600	4	2.6	Q1		V▲	V▲				V▲		Rds-on 2.5 Ohm
P0660	600	6	1.25	Now						V▲	V▲		
P0660B	600	6	1.5	Q1		V▲	V▲				V▲		Possible for TO-252
P1060B	600	10	1	Q2							V▲		
P1060	600	10	0.75	Now						V▲	V▲		
P1260	600	12	0.65	Now						V▲	V▲		
P0165	650	1	14	Now		V▲	V▲				V▲		
P0265	650	2	5.5	Q1		V▲	V▲				V▲		
P0465	650	4	2.5	Q1		V▲	V▲				V▲		
P0765	650	7	1.5	Now							V▲		
P1065	650	10	0.75	Now							V▲		
P0170	700	1	15	Now	V▲	V▲	V▲						
P0270	700	2	6	Q1		V▲	V▲				V▲		
P0470	700	4	2.8	Q1		V▲	V▲				V▲		
P0770	700	7	1.7	Q1							V▲		
P1070	700	10	0.85	Now							V▲		